# 74LV259

# 8-bit addressable latch Rev. 4 — 9 March 2016

**Product data sheet** 

#### **General description** 1.

The 74LV259 is a low-voltage Si-gate CMOS device that is pin and function compatible with 74HC259 and 74HCT259. The 74LV259 is a high-speed 8-bit addressable latch designed for general purpose storage applications in digital systems. The 74LV259 is multifunctional device capable of storing single-line data in eight addressable latches, and also 3-to-8 decoder and demultiplexer, with active HIGH outputs (Q0 to Q7), functions are available. The 74LV259 also incorporates an active LOW common reset (MR) for resetting all latches, as well as, an active LOW enable input (LE).

The 74LV259 has four modes of operation as shown in the mode select table. In the addressable latch mode, data on the data line (D) is written into the addressed latch. The addressed latch will follow the data input with all non-addressed latches remaining in their previous states. In the memory mode, all latches remain in their previous states and are unaffected by the data or address inputs. In the 3-to-8 decoding or demultiplexing mode, the addressed output follows the state of the (D) input with all other outputs in the LOW state. In the reset mode all outputs are LOW and unaffected by the address (A0 to A2) and data (D) input. When operating the 74LV259 as an address latch, changing more than one bit of address could impose a transient-wrong address. Therefore, this should only be done while in the memory mode.

#### 2. Features and benefits

- Optimized for low voltage applications: 1.0 V to 3.6 V
- Accepts TTL input levels between V<sub>CC</sub> = 2.7 V and V<sub>CC</sub> = 3.6 V
- Typical output ground bounce < 0.8 V at V<sub>CC</sub> = 3.3 V and T<sub>amb</sub> = 25 °C
- Typical HIGH-level output voltage (V<sub>OH</sub>) undershoot: > 2 V at V<sub>CC</sub> = 3.3 V and  $T_{amb} = 25 \, ^{\circ}C$
- Combines demultiplexer and 8-bit latch
- Serial-to-parallel capability
- Output from each storage bit available
- Random (addressable) data entry
- Easily expandable
- Common reset input
- Useful as a 3-to-8 active HIGH decoder
- ESD protection:
  - HBM JESD22-A114E exceeds 2000 V
  - MM JESD22-A115-A exceeds 200 V
- Multiple package options
- Specified from -40 °C to +85 °C and from -40 °C to +125 °C



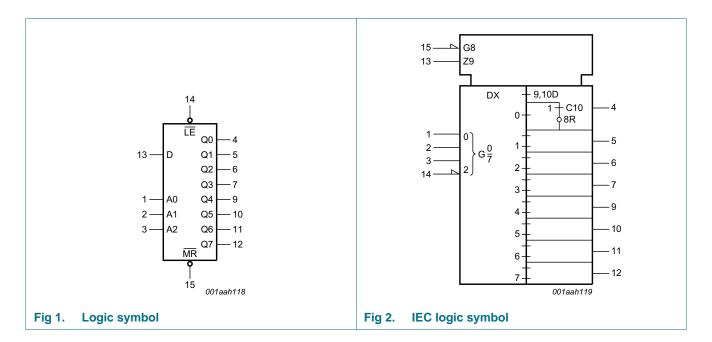
#### 8-bit addressable latch

# 3. Ordering information

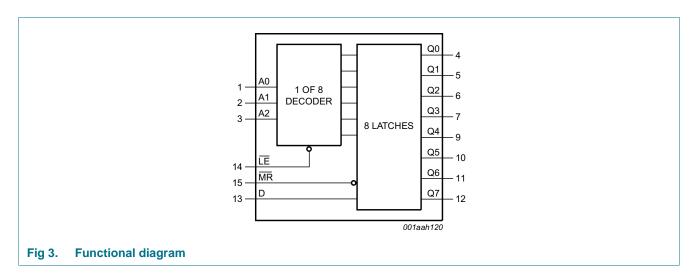
Table 1. Ordering information

Type number	Package			
	Temperature range	Name	Description	Version
74LV259D	–40 °C to +125 °C	SO16	plastic small outline package; 16 leads; body width 3.9 mm	SOT109-1
74LV259DB	–40 °C to +125 °C	SSOP16	plastic shrink small outline package; 16 leads; body width 5.3 mm	SOT338-1
74LV259PW	-40 °C to +125 °C	TSSOP16	plastic thin shrink small outline package; 16 leads; body width 4.4 mm	SOT403-1
74LV259BQ	-40 °C to +125 °C	DHVQFN16	plastic dual in-line compatible thermal enhanced very thin quad flat package; no leads; 16 terminals; body $2.5\times3.5\times0.85$ mm	SOT763-1

# 4. Functional diagram

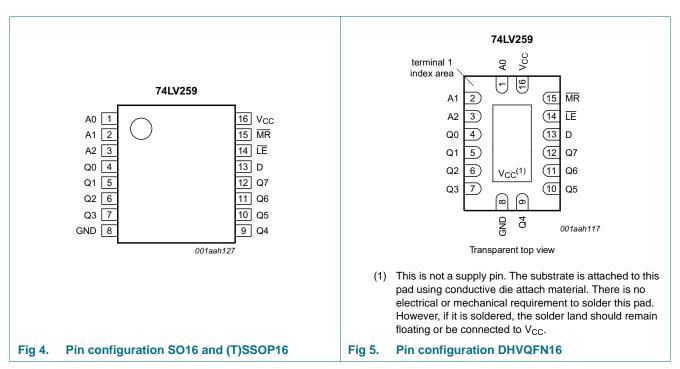


#### 8-bit addressable latch



# 5. Pinning information

### 5.1 Pinning



### 5.2 Pin description

Table 2. Pin description

Symbol	Pin	Description
A0	1	address input
A1	2	address input
A2	3	address input
GND	8	ground (0 V)

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Table 2. Pin description ...continued

Symbol	Pin	Description
Q[0:7]	4, 5, 6, 7, 9, 10, 11, 12	latch output
D	13	data input
LE	14	latch enable input (active LOW)
MR	15	conditional reset input (active LOW)
V <sub>CC</sub>	16	supply voltage

# 6. Functional description

#### Table 3. Mode select table

 $H = HIGH \ voltage \ level; \ L = LOW \ voltage \ level$ 

LE	MR	Mode
L	Н	addressable latch
Н	Н	memory
L	L	active HIGH 8-channel demultiplexer
Н	L	reset

#### Table 4. Function table

 $H = HIGH \ voltage \ level; \ L = LOW \ voltage \ level; \ X = don't \ care; \ d = High \ or \ LOW \ data \ one \ set-up \ time \ prior \ to \ the \ LOW-to-HIGH \ LE \ transition; \ q<n> = state \ of \ the \ output \ established \ during \ the \ last \ cycle \ in \ which \ it \ was \ addressed \ or \ cleared$ 

Operating modes	Input						Output							
	MR	LE	D	A0	A1	A2	Q0	Q1	Q2	Q3	Q4	Q5	Q6	Q7
master reset	L	Н	Х	Х	Х	Х	L	L	L	L	L	L	L	L
demultiplex (active	L	L	d	L	L	L	Q = d	L	L	L	L	L	L	L
HIGH) decoder (when D = H)	L	L	d	Н	L	L	L	Q = d	L	L	L	L	L	L
(when b = 11)	L	L	d	L	Н	L	L	L	Q = d	L	L	L	L	L
	L	L	d	Н	Н	L	L	L	L	Q = d	L	L	L	L
	L	L	d	L	L	Н	L	L	L	L	Q = d	L	L	L
	L	L	d	Н	L	Н	L	L	L	L	L	Q = d		L
	L	L	d	L	Н	Н	L	L	L	L	L	L	Q = d	L
	L	L	d	Н	Н	Н	L	L	L	L	L	L	L	Q = d
store (do nothing)	Н	Н	Χ	Х	Х	X	q0	q1	q2	q3	q4	q5	q6	q7
addressable latch	Н	L	d	L	L	L	Q = d	q1	q2	q3	q4	q5	q6	q7
	Н	L	d	Н	L	L	q0	Q = d	q2	q3	q4	q5	q6	q7
	Н	L	d	L	Н	L	q0	q1	Q = d	q3	q4	q5	q6	q7
	Н	L	d	Н	Н	L	q0	q1	q2	Q = d	q4	q5	q6	q7
	Н	L	d	L	L	Н	q0	q1	q2	q3	Q = d	q5	q6	q7
	Н	L	d	Н	L	Н	q0	q1	q2	q3	q4	Q = d	q6	q7
	Н	L	d	L	Н	Н	q0	q1	q2	q3	q4	q5	Q = d	q7
	Н	L	Н	Н	Н	Н	q0	q1	q2	q3	q4	q5	q6	Q = d

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# 7. Limiting values

Table 5. Limiting values

In accordance with the Absolute Maximum Rating System (IEC 60134). Voltages are referenced to GND (ground = 0 V).

Symbol	Parameter	Conditions		Min	Max	Unit
V <sub>CC</sub>	supply voltage			-0.5	+4.6	V
I <sub>IK</sub>	input clamping current	$V_{I} < -0.5 \text{ V or } V_{I} > V_{CC} + 0.5 \text{ V}$	<u>[1]</u>	-	±20	mA
I <sub>OK</sub>	output clamping current	$V_{O} < -0.5 \text{ V or } V_{O} > V_{CC} + 0.5 \text{ V}$	<u>[1]</u>	-	±50	mA
Io	output current	$V_{O} = -0.5 \text{ V to } (V_{CC} + 0.5 \text{ V})$		-	±25	mA
I <sub>CC</sub>	supply current			-	50	mA
I <sub>GND</sub>	ground current			-50	-	mA
T <sub>stg</sub>	storage temperature			-65	+150	°C
P <sub>tot</sub>	total power dissipation	$T_{amb} = -40  ^{\circ}\text{C} \text{ to } +125  ^{\circ}\text{C}$				
		SO16 package	[2]	-	500	mW
		(T)SSOP16 package	[3]	-	500	mW
		DHVQFN16 package	<u>[4]</u>	-	500	mW

<sup>[1]</sup> The input and output voltage ratings may be exceeded if the input and output current ratings are observed.

# 8. Recommended operating conditions

Table 6. Recommended operating conditions

Voltages are referenced to GND (ground = 0 V).

Symbol	Parameter	Conditions	Min	Тур	Max	Unit
V <sub>CC</sub>	supply voltage	[1]	1.0	3.3	3.6	V
VI	input voltage		0	-	V <sub>CC</sub>	V
Vo	output voltage		0	-	V <sub>CC</sub>	V
T <sub>amb</sub>	ambient temperature		-40	+25	+125	°C
Δt/ΔV	input transition rise and fall rate	V <sub>CC</sub> = 1.0 V to 2.0 V	-	-	500	ns/V
		V <sub>CC</sub> = 2.0 V to 2.7 V	-	-	200	ns/V
		V <sub>CC</sub> = 2.7 V to 3.6 V	-	-	100	ns/V

<sup>[1]</sup> The static characteristics are guaranteed from  $V_{CC}$  = 1.2 V to  $V_{CC}$  = 5.5 V, but LV devices are guaranteed to function down to  $V_{CC}$  = 1.0 V (with input levels GND or  $V_{CC}$ ).

<sup>[2]</sup> Ptot derates linearly with 8 mW/K above 70 °C.

<sup>[3]</sup> Ptot derates linearly with 5.5 mW/K above 60 °C.

<sup>[4]</sup> Ptot derates linearly with 4.5 mW/K above 60 °C.

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# 9. Static characteristics

Table 7. Static characteristics

Voltages are referenced to GND (ground = 0 V).

Symbol	Parameter	Conditions	-40	°C to +8	5 °C	-40 °C to	+125 °C	Unit
			Min	Typ[1]	Max	Min	Max	
V <sub>IH</sub>	HIGH-level input voltage	V <sub>CC</sub> = 1.2 V	0.9	-	-	0.9	-	V
		V <sub>CC</sub> = 2.0 V	1.4	-	-	1.4	-	V
		$V_{CC} = 2.7 \text{ V to } 3.6 \text{ V}$	2.0	-	-	2.0	-	V
$V_{IL}$	LOW-level input voltage	V <sub>CC</sub> = 1.2 V	-	-	0.3	-	0.3	V
		V <sub>CC</sub> = 2.0 V	-	-	0.6	-	0.6	V
		$V_{CC} = 2.7 \text{ V to } 3.6 \text{ V}$	-	-	0.8	-	0.8	V
V <sub>OH</sub>	HIGH-level output voltage	$V_I = V_{IH}$ or $V_{IL}$						
		$I_O = -100 \mu A; V_{CC} = 1.2 V$	-	1.2	-	-	-	V
		$I_O = -100 \mu A; V_{CC} = 2.0 V$	1.8	2.0	-	1.8	-	V
		$I_O = -100 \mu A; V_{CC} = 2.7 V$	2.5	2.7	-	2.5	-	V
		$I_O = -100 \mu A; V_{CC} = 3.0 V$	2.8	3.0	-	2.8	-	V
		$I_O = -6 \text{ mA}; V_{CC} = 3.0 \text{ V}$	2.4	2.82	-	2.2	-	V
$V_{OL}$	LOW-level output voltage	$V_I = V_{IH}$ or $V_{IL}$						
		$I_O = 100 \mu A; V_{CC} = 1.2 V$	-	0	-	-	-	V
		$I_O = 100 \mu A; V_{CC} = 2.0 \text{ V}$	-	0	0.2	-	0.2	V
		$I_O = 100 \mu A; V_{CC} = 2.7 V$	-	0	0.2	-	0.2	V
		$I_O = 100 \mu A; V_{CC} = 3.0 \text{ V}$	-	0	0.2	-	0.2	V
		$I_{O} = 6 \text{ mA}; V_{CC} = 3.0 \text{ V}$	-	0.25	0.40	-	0.50	V
l <sub>l</sub>	input leakage current	$V_I = V_{CC}$ or GND; $V_{CC} = 5.5 \text{ V}$	-	-	1.0	-	1.0	μΑ
I <sub>CC</sub>	supply current	$V_I = V_{CC}$ or GND; $I_O = 0$ A; $V_{CC} = 5.5 \text{ V}$	-	-	20.0	-	160	μΑ
Δl <sub>CC</sub>	additional supply current	per input; $V_1 = V_{CC} - 0.6 \text{ V}$ ; $V_{CC} = 2.7 \text{ V}$ to 3.6 V	-	-	500	-	850	μА
Cı	input capacitance		-	3.5	-	-	-	pF

<sup>[1]</sup> Typical values are measured at  $T_{amb}$  = 25 °C.

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# 10. Dynamic characteristics

Table 8. Dynamic characteristics

GND = 0 V; For test circuit see Figure 12.

Symbol	Parameter	Conditions		-40	°C to +8	5 °C	–40 °C to	+125 °C	Unit
				Min	Typ[1]	Max	Min	Max	
t <sub>pd</sub>	propagation delay	D to Qn; see Figure 8	[2]						
		V <sub>CC</sub> = 1.2 V		-	105	-	-	-	ns
		V <sub>CC</sub> = 2.0 V		-	36	49	-	61	ns
		V <sub>CC</sub> = 2.7 V		-	26	36	-	45	ns
		$V_{CC} = 3.0 \text{ V to } 3.6 \text{ V; } C_L = 15 \text{ pF}$	[3]	-	17	-	-	-	ns
		V <sub>CC</sub> = 3.0 V to 3.6 V	[3]	-	20	29	-	36	ns
t <sub>pd</sub>	propagation delay	An to Qn; see Figure 7	[2]						
		V <sub>CC</sub> = 1.2 V		-	105	-	-	-	ns
		V <sub>CC</sub> = 2.0 V		-	36	49	-	61	ns
		V <sub>CC</sub> = 2.7 V		-	26	36	-	45	ns
		$V_{CC} = 3.0 \text{ V to } 3.6 \text{ V; } C_L = 15 \text{ pF}$	[3]	-	17	-	-	-	ns
		V <sub>CC</sub> = 3.0 V to 3.6 V	[3]	-	20	29	-	36	ns
t <sub>pd</sub>	propagation delay	LE to Qn; Figure 6	[2]						
		V <sub>CC</sub> = 1.2 V		-	100	-	-	-	ns
		V <sub>CC</sub> = 2.0 V		-	34	48	-	60	ns
		V <sub>CC</sub> = 2.7 V		-	25	35	-	44	ns
		$V_{CC} = 3.0 \text{ V to } 3.6 \text{ V; } C_L = 15 \text{ pF}$	[3]	-	16	-	-	-	ns
		V <sub>CC</sub> = 3.0 V to 3.6 V	[3]	-	19	28	-	35	ns
t <sub>PHL</sub>	HIGH to LOW	MR to Qn; Figure 9							
	propagation delay	V <sub>CC</sub> = 1.2 V		-	90	-	-	-	ns
		V <sub>CC</sub> = 2.0 V		-	31	43	-	53	ns
		V <sub>CC</sub> = 2.7 V		-	23	31	-	39	ns
		$V_{CC} = 3.0 \text{ V to } 3.6 \text{ V; } C_L = 15 \text{ pF}$	[3]	-	14	-	-	-	ns
		V <sub>CC</sub> = 3.0 V to 3.6 V	[3]	-	17	25	-	31	ns
t <sub>W</sub>	pulse width	LE, HIGH or LOW; see Figure 6							
		V <sub>CC</sub> = 2.0 V		34	10	-	41	-	ns
		V <sub>CC</sub> = 2.7 V		25	8	-	30	-	ns
		V <sub>CC</sub> = 3.0 V to 3.6 V	[3]	20	6	-	24	-	ns
t <sub>W</sub>	pulse width	MR, LOW; see Figure 9							
		V <sub>CC</sub> = 2.0 V		34	10	-	41	-	ns
		V <sub>CC</sub> = 2.7 V		25	8	-	30	-	ns
		V <sub>CC</sub> = 3.0 V to 3.6 V	[3]	20	6	-	24	-	ns

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Table 8. Dynamic characteristics ...continued

GND = 0 V; For test circuit see <u>Figure 12</u>.

Symbol	Parameter	Conditions		-40	°C to +8	5 °C	-40 °C to	+125 °C	Unit
			-	Min	Typ[1]	Max	Min	Max	
t <sub>su</sub>	set-up time	D, An to LE; see Figure 10 and Figure 11							
		V <sub>CC</sub> = 1.2 V		-	35	-	-	-	ns
		V <sub>CC</sub> = 2.0 V		24	12	-	29	-	ns
		V <sub>CC</sub> = 2.7 V		18	9	-	21	-	ns
		V <sub>CC</sub> = 3.0 V to 3.6 V	[3]	14	7	-	17	-	ns
t <sub>h</sub>	hold time	D to LE; see Figure 10							
		V <sub>CC</sub> = 1.2 V		-	-30	-	-	-	ns
		V <sub>CC</sub> = 2.0 V		5	-10	-	5	-	ns
		V <sub>CC</sub> = 2.7 V		5	-8	-	5	-	ns
		V <sub>CC</sub> = 3.0 V to 3.6 V	[3]	5	-6	-	5	-	ns
t <sub>h</sub>	hold time	An to LE; see Figure 11							
		V <sub>CC</sub> = 1.2 V		-	-20	-	-	-	ns
		V <sub>CC</sub> = 2.0 V		5	-7	-	5	-	ns
		V <sub>CC</sub> = 2.7 V		5	-5	-	5	-	ns
		V <sub>CC</sub> = 3.0 V to 3.6 V	[3]	5	-4	-	5	-	ns
C <sub>PD</sub>	power dissipation capacitance	$C_L = 50 \text{ pF}; f_i = 1 \text{ MHz};$ $V_I = \text{GND to } V_{CC}$	<u>[4]</u>	-	19	-	-	-	pF

- [1] Typical values are measured at  $T_{amb} = 25$  °C.
- [2]  $t_{pd}$  is the same as  $t_{PLH}$  and  $t_{PHL}$ .
- [3] Typical value measured at  $V_{CC} = 3.3 \text{ V}$ .
- [4]  $C_{PD}$  is used to determine the dynamic power dissipation ( $P_D$  in  $\mu W$ ).

$$P_D = C_{PD} \times V_{CC}{}^2 \times f_i \times N + \sum (C_L \times V_{CC}{}^2 \times f_o)$$
 where:

 $f_i$  = input frequency in MHz;

f<sub>o</sub> = output frequency in MHz;

C<sub>L</sub> = output load capacitance in pF;

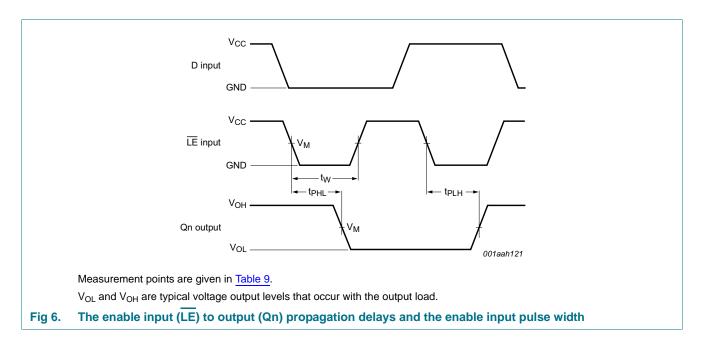
 $V_{CC}$  = supply voltage in V;

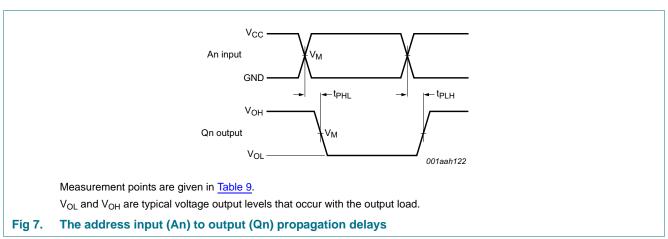
N = number of inputs switching;

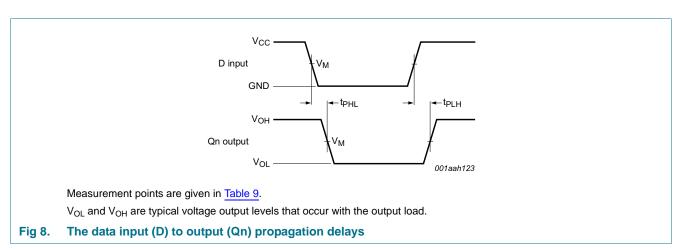
 $\sum (C_L \times V_{CC}^2 \times f_o) = sum of outputs.$ 

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### 11. Waveforms







8-bit addressable latch

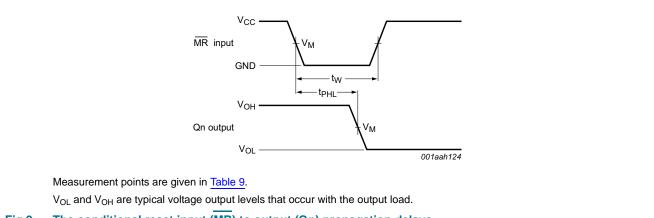
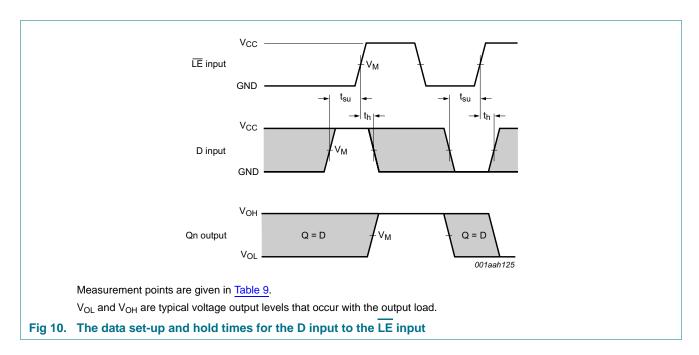


Fig 9. The conditional reset input (MR) to output (Qn) propagation delays



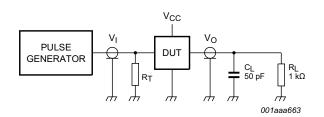
An input

An inp

#### 8-bit addressable latch

Table 9. Measurement points

Supply voltage	Input	Output
V <sub>CC</sub>	V <sub>M</sub>	V <sub>M</sub>
< 2.7 V	0.5V <sub>CC</sub>	0.5V <sub>CC</sub>
2.7 V to 3.6 V	1.5 V	1.5 V



Test data is given in Table 10.

Definitions test circuit:

 $R_T$  = Termination resistance should be equal to output impedance  $Z_o$  of the pulse generator.

R<sub>L</sub> = Load resistance.

 $C_L$  = Load capacitance including jig and probe capacitance.

Fig 12. Test circuit for measuring switching times

#### Table 10. Test data

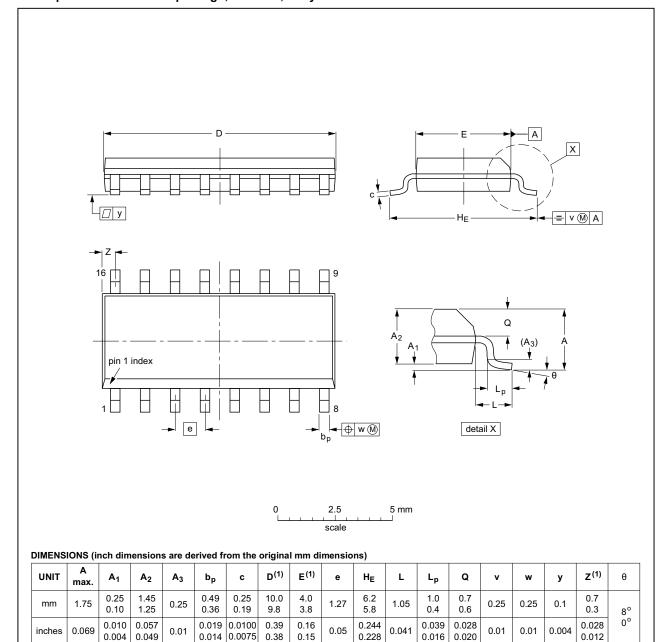
Supply voltage	Input				
V <sub>CC</sub>	V <sub>I</sub>	t <sub>r</sub> , t <sub>f</sub>			
< 2.7 V	V <sub>CC</sub>	≤ 2.5 ns			
2.7 V to 3.6 V	2.7 V	≤ 2.5 ns			

#### 8-bit addressable latch

# 12. Package outline

SO16: plastic small outline package; 16 leads; body width 3.9 mm

SOT109-1



#### Note

1. Plastic or metal protrusions of 0.15 mm (0.006 inch) maximum per side are not included.

OUTLINE		REFER	ENCES	EUROPEAN	ISSUE DATE
VERSION	IEC	JEDEC	JEITA	PROJECTION	ISSUE DATE
SOT109-1	076E07	MS-012			<del>99-12-27</del> 03-02-19

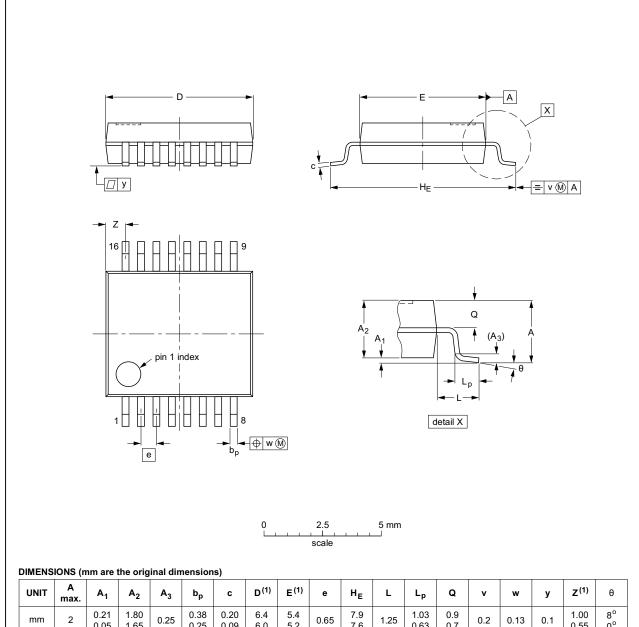
Fig 13. Package outline SOT109-1 (SO16)

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74LV259 **NXP Semiconductors** 

SSOP16: plastic shrink small outline package; 16 leads; body width 5.3 mm

SOT338-1



UNIT	A max.	A <sub>1</sub>	A <sub>2</sub>	<b>A</b> <sub>3</sub>	b <sub>p</sub>	U	D <sup>(1)</sup>	E <sup>(1)</sup>	е	HE	L	Lp	Q	>	w	у	Z <sup>(1)</sup>	θ
mm	2	0.21 0.05	1.80 1.65	0.25	0.38 0.25	0.20 0.09	6.4 6.0	5.4 5.2	0.65	7.9 7.6	1.25	1.03 0.63	0.9 0.7	0.2	0.13	0.1	1.00 0.55	8° 0°

#### Note

1. Plastic or metal protrusions of 0.25 mm maximum per side are not included.

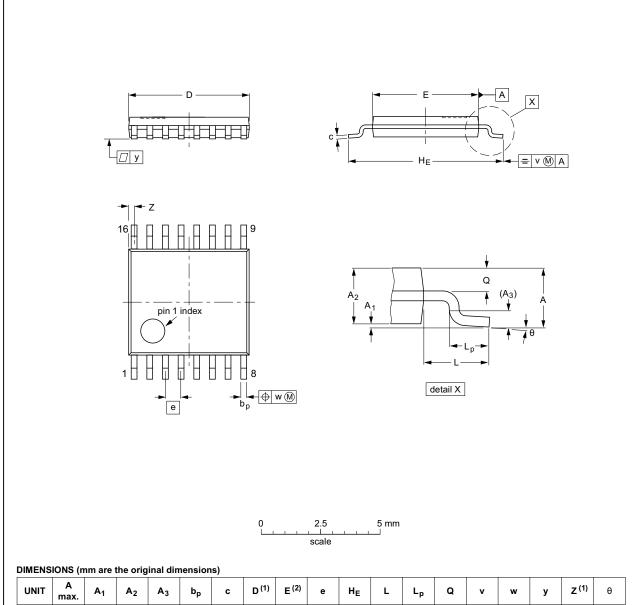
OUTLINE		REFER	RENCES	EUROPEAN	ISSUE DATE
VERSION	IEC	JEDEC	JEITA	PROJECTION	1330E DATE
SOT338-1		MO-150			<del>99-12-27</del> 03-02-19

Fig 14. Package outline SOT338-1 (SSOP16)

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TSSOP16: plastic thin shrink small outline package; 16 leads; body width 4.4 mm

SOT403-1



UNIT	A max.	A <sub>1</sub>	A <sub>2</sub>	<b>A</b> <sub>3</sub>	bp	С	D <sup>(1)</sup>	E (2)	е	HE	L	Lp	Q	٧	w	у	Z <sup>(1)</sup>	θ
mm	1.1	0.15 0.05	0.95 0.80	0.25	0.30 0.19	0.2 0.1	5.1 4.9	4.5 4.3	0.65	6.6 6.2	1	0.75 0.50	0.4 0.3	0.2	0.13	0.1	0.40 0.06	8° 0°

#### Notes

- 1. Plastic or metal protrusions of 0.15 mm maximum per side are not included.
- 2. Plastic interlead protrusions of 0.25 mm maximum per side are not included.

OUTLINE		REFER	RENCES		EUROPEAN	ISSUE DATE
VERSION	IEC	JEDEC	JEDEC JEITA		PROJECTION	ISSUE DATE
SOT403-1		MO-153				<del>-99-12-27</del> 03-02-18
SOT403-1		MO-153				<u> </u>

Fig 15. Package outline SOT403-1 (TSSOP16)

74I V/259

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DHVQFN16: plastic dual in-line compatible thermal enhanced very thin quad flat package; no leads; 16 terminals; body 2.5 x 3.5 x 0.85 mm SOT763-1

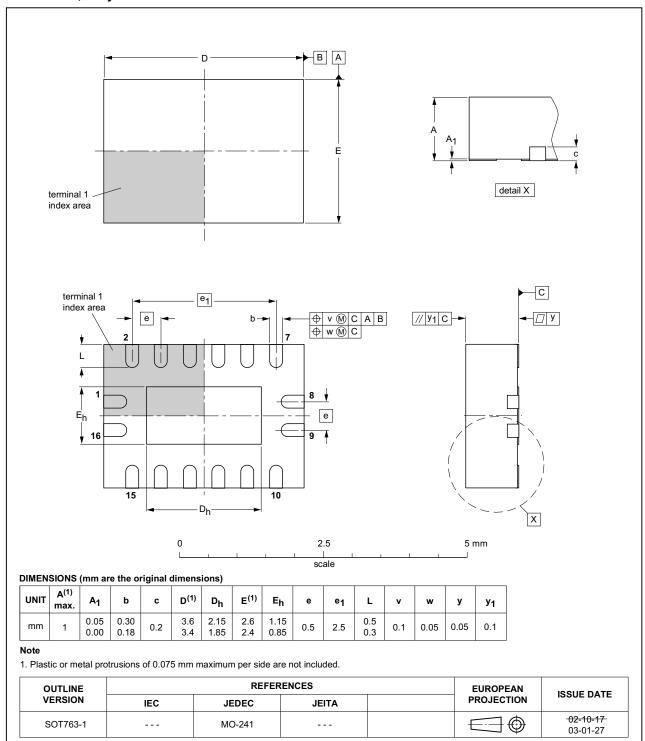


Fig 16. Package outline SOT763-1 (DHVQFN16)

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# 13. Abbreviations

#### Table 11. Abbreviations

Acronym	Description
CMOS	Complementary Metal Oxide Semiconductor
DUT	Device Under Test
ESD	ElectroStatic Discharge
НВМ	Human Body Model
MM	Machine Model
TTL	Transistor-Transistor Logic

# 14. Revision history

#### Table 12. Revision history

Document ID	Release date	Data sheet status	Change notice	Supersedes					
74LV259 v.4	20160309	Product data sheet	-	74LV259 v.3					
Modifications:	Type number 74LV2	259N (SOT38-4) removed	i.						
74LV259 v.3	20080102	Product data sheet	-	74LV259 v.2					
Modifications:	<ul> <li>The format of this data sheet has been redesigned to comply with the new identity guidelines of NXP Semiconductors.</li> </ul>								
	<ul> <li>Legal texts have been adapted to the new company name where appropriate.</li> </ul>								
	<ul> <li>Section 3: DHVQFN16 package added.</li> </ul>								
	<ul> <li><u>Section 7</u>: derating values added for DHVQFN16 package.</li> </ul>								
	<ul> <li>Section 12: outline drawing added for DHVQFN16 package.</li> </ul>								
74LV259 v.2	19980520	Product specification	-	74LV259 v.1					
74LV259 v.1	19970606	Product specification	-	-					

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### 15. Legal information

#### 15.1 Data sheet status

Document status[1][2]	Product status[3]	Definition
Objective [short] data sheet	Development	This document contains data from the objective specification for product development.
Preliminary [short] data sheet	Qualification	This document contains data from the preliminary specification.
Product [short] data sheet	Production	This document contains the product specification.

- [1] Please consult the most recently issued document before initiating or completing a design.
- [2] The term 'short data sheet' is explained in section "Definitions"
- [3] The product status of device(s) described in this document may have changed since this document was published and may differ in case of multiple devices. The latest product status information is available on the Internet at URL http://www.nxp.com.

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